

MJLP2951-X REV 1B1

Original Creation Date: 08/01/95
Last Update Date: 05/19/98
Last Major Revision Date: 01/21/97

ADJUSTABLE MICROPPOWER VOLTAGE REGULATORS
General Description

The LP2951 is a micropower voltage regulator with very low quiescent current (75 uA typ.) and very low dropout voltage (typ. 40 mV at light loads and 380 mV at 100mA). They are ideally suited for use in battery-powered systems. Furthermore, the quiescent current of the LP2951 increases only slightly in dropout, prolonging battery life.

The 8-Lead LP2951 is available in plastic, ceramic dual-in-line, or metal can packages and offers additional system functions.

One such feature is an error flag output which warns of a low output voltage, often due to falling batteries on the input. It may be used for a power-on reset. A second feature is the logic-compatible shutdown input which enables the regulator to be switched on and off. Also, the part may be pin-strapped for a 5V output or programmed from 1.24V to 29V with an external pair of resistors.

Careful design of the LP2951 has minimized all contributions to the error budget. This includes a tight initial tolerance (.5% typ.), extremely good load and line regulation (.05% typ.) and a very low output voltage temperature coefficient, making the part useful as a low-power voltage reference.

Industry Part Number

LP2951

Prime Die

LP2951

NS Part Numbers

JL2951BGA*
JL2951BPA**
JL2951S2A***
JL2951SGA****
JL2951SPA*****

Controlling Document

See Features Page REV C

Processing

MIL-STD-883, Method 5004

Quality Conformance Inspection

MIL-STD-883, Method 5005

Subgrp Description
Temp (°C)

1	Static tests at	+25
2	Static tests at	+125
3	Static tests at	-55
4	Dynamic tests at	+25
5	Dynamic tests at	+125
6	Dynamic tests at	-55
7	Functional tests at	+25
8A	Functional tests at	+125
8B	Functional tests at	-55
9	Switching tests at	+25
10	Switching tests at	+125
11	Switching tests at	-55

Features

- SMD : 5962-3870501BGA*, BPA**, S2A***, SGA****, SPA*****.

(Absolute Maximum Ratings)

(Note 1)

Power Dissipation

(Note 2)

METAL CAN	675mW at +25 C
CERDIP	1.0W at +25 C
LCC	1.25W at +25 C
CERAMIC SOIC	1.0W at +25 C

Lead Temperature

(Soldering, 10 seconds)

260 C

Storage Temperature Range

-65 C to +150 C

Operating Junction Temp Range

LP2951

-55 C to +160 C

Input Supply Voltage

-0.3 to +30V

Feedback Input Voltage

(Note 3, 4)

-1.5 to +30V

Shutdown Input Voltage

(Note 3)

-0.3 to +30V

Error Comparator Out. Voltage

(Note 3)

-0.3 to +30V

Thermal Resistance

ThetaJA

METAL CAN	(Still Air @ 0.5W)	163 C/W
	(500LF/Min Air flow @ 0.5W)	95 C/W
CERDIP	(Still Air @ 0.5W)	131 C/W
	(500LF/Min Air flow @ 0.5W)	75 C/W
LCC	(Still Air @ 0.5W)	95 C/W
	(500LF/Min Air flow @ 0.5W)	66 C/W
CERAMIC SOIC	(Still Air @ 0.5W)	215 C/W
	(500LF/Min Air flow @ 0.5W)	130 C/W

ThetaJC

METAL CAN	51 C/W
CERDIP	21 C/W
LCC	24 C/W
CERAMIC SOIC	24 C/W

Package Weight

(Typical)

TBD

ESD Rating

500V

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

Note 2: The maximum power dissipation must be derated at elevated temperatures and is dictated by Tjmax (maximum junction temperature), ThetaJA (package junction to ambient thermal resistance), and TA (ambient temperature). The maximum allowable power dissipation at any temperature is $P_{dmax} = (T_{jmax} - T_A)/\Theta_{JA}$ or the number given in the Absolute Maximum Ratings, whichever is lower.

Note 3: May exceed input supply voltage.

Note 4: When used in dual-supply systems where the output terminal sees loads returned to a negative supply, the output voltage should be diode-clamped to ground.

Electrical Characteristics

DC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)

DC: $V_{out} = 5V$ (Nominal), $C_{load} = 3.3\mu F$, $V_{sd} = 0.6V$, $V_{in} = 6V$, $I_l = -100\mu A$

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
V_o	Output Voltage	$V_{in} = 6V$, $I_l = -100\mu A$			4.975	5.025	V	1
					4.94	5.06	V	2, 3
V_{oline}	Line Regulation	$6V \leq V_{in} \leq 30V$, $I_l = -1mA$			-5	5	mV	1
		$6V \leq V_{in} \leq 30V$, $I_l = -1mA$			-25	25	mV	2, 3
V_{oload}	Load Regulation	$-100\mu A \leq I_l \leq -100mA$, $V_{in} = 6V$			-5	5	mV	1
		$-100\mu A \leq I_l \leq -100mA$, $V_{in} = 6V$			-25	25	mV	2, 3
V_d	Dropout Voltage	$I_l = -100mA$				450	mV	1
						600	mV	2, 3
		$I_l = -100\mu A$				80	mV	1
						150	mV	2, 3
I_g	Ground Current	$I_l = -100mA$, $V_{in} = 6V$				12	mA	1
						14	mA	2, 3
		$I_l = -100\mu A$, $V_{in} = 6V$				120	μA	1
						140	μA	2, 3
		$I_l = -100\mu A$, $V_{out} = 15V$, $V_{in} = 30V$				120	μA	1
						140	μA	2, 3
		$I_l = -100\mu A$, $V_{in} = 30V$, $V_{out} = 15V$				15	mA	1
						20	mA	2, 3
I_{gdiff}	Ground Current Change	$6V \leq V_{in} \leq 30V$, $I_l = -100\mu A$			-30	30	μA	1
		$6V \leq V_{in} \leq 30V$, $I_l = -100\mu A$			-50	50	μA	2, 3
I_{gdo}	Dropout Ground Current	$V_{in} = 4.5V$, $I_l = -100\mu A$				170	μA	1
						200	μA	2, 3
V_{lt}	Error Comparator Lower Threshold Voltage	$V_{in} = 6V$, $I_l = -100\mu A$	1		0	0.8	mV	1, 2, 3
V_{ut}	Error Comparator Upper Threshold Voltage	$V_{in} = 6V$, $I_l = -100\mu A$	1		2	30	mV	1, 2, 3
V_{rth}	Thermal Regulation	$V_{in} = 30V$, $I_l = -50mA$, $2mS \leq T \leq 10mS$			-12.5	12.5	mV	1
I_{sc}	Current Limit	$V_{out} = 0V$, $V_{in} = 6V$				200	mA	1
						220	mA	2, 3

Electrical Characteristics

DC PARAMETERS(Continued)

(The following conditions apply to all the following parameters, unless otherwise specified.)

DC: $V_{out} = 5V$ (Nominal), $C_{load} = 3.3\mu F$, $V_{sd} = 0.6V$, $V_{in} = 6V$, $I_l = -100\mu A$

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
Igsc	Ground Current At Current Limit	$V_{out} = 0V$, $V_{in} = 6V$				20	mA	1
						25	mA	2, 3
Vref	Reference Voltage				1.22	1.25	V	1
					1.20	1.26	V	2, 3
Vrline	Reference Voltage Line Regulation	$2.3V \leq V_{in} \leq 30V$			-1.9	1.9	mV	1
		$2.3V \leq V_{in} \leq 30V$			-10	10	mV	2, 3
Vrload	Reference Voltage Output Regulation	$1.2V \leq V_{out} \leq 29V$, $V_{in} = 30V$			-1.2	1.2	mV	1
		$1.2V \leq V_{out} \leq 29V$, $V_{in} = 30V$			-5	5	mV	2, 3
Ifb	Feedback Pin Bias Current					40	nA	1
						60	nA	2, 3
Ioh	Error Comparator Output Leakage Current	$V_o = 30V$				1	uA	1
						2	uA	2, 3
Vol	Error Comparator Output Low Voltage	$V_{in} = 4.5V$, $V_{sd} = 2V$				250	mV	1
						400	mV	2, 3
Isd	Shutdown Pin Input Current	$V_{sd} = 2.4V$				50	uA	1
						100	uA	2, 3
		$V_{sd} = 30V$				600	uA	1
						750	uA	2, 3
Vsdl	Shutdown Input Logic Voltage	(LOW)	1			0.6	V	1, 2, 3
Vsdh	Shutdown Input Logic Voltage	(HIGH)	1		2		V	1, 2, 3
Ilkg	Regular Output Bias Current In Shutdown	$V_{sd} = 2V$, $V_{in} = 30V$, $I_l = 0mA$			-10	10	uA	1
					-20	20	uA	2, 3

AC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)

AC: $V_{in} = 6V$, $C_{load} = 3.3\mu F$, $V_{sd} = 0.6V$

Rr	Ripple Rejection	$f = 120Hz$, $V_{in} = 0.1V_{rms}$			50		dB	4
Vnoise	Output Noise	$C_1 = 1\mu F$				600	uVrms	7
		$C_1 = 3.3\mu F$				250	uVrms	7

Electrical Characteristics

DC PARAMETERS: DRIFT VALUES

(The following conditions apply to all the following parameters, unless otherwise specified.)

DC: Vout = 5V (Nominal), Cload = 3.3uF, Vsd = 0.6V, Vin = 6V, Il = -100uA. "Delta calculations performed on JAN S and QMLV devices at group B, subgroup 5 ONLY."

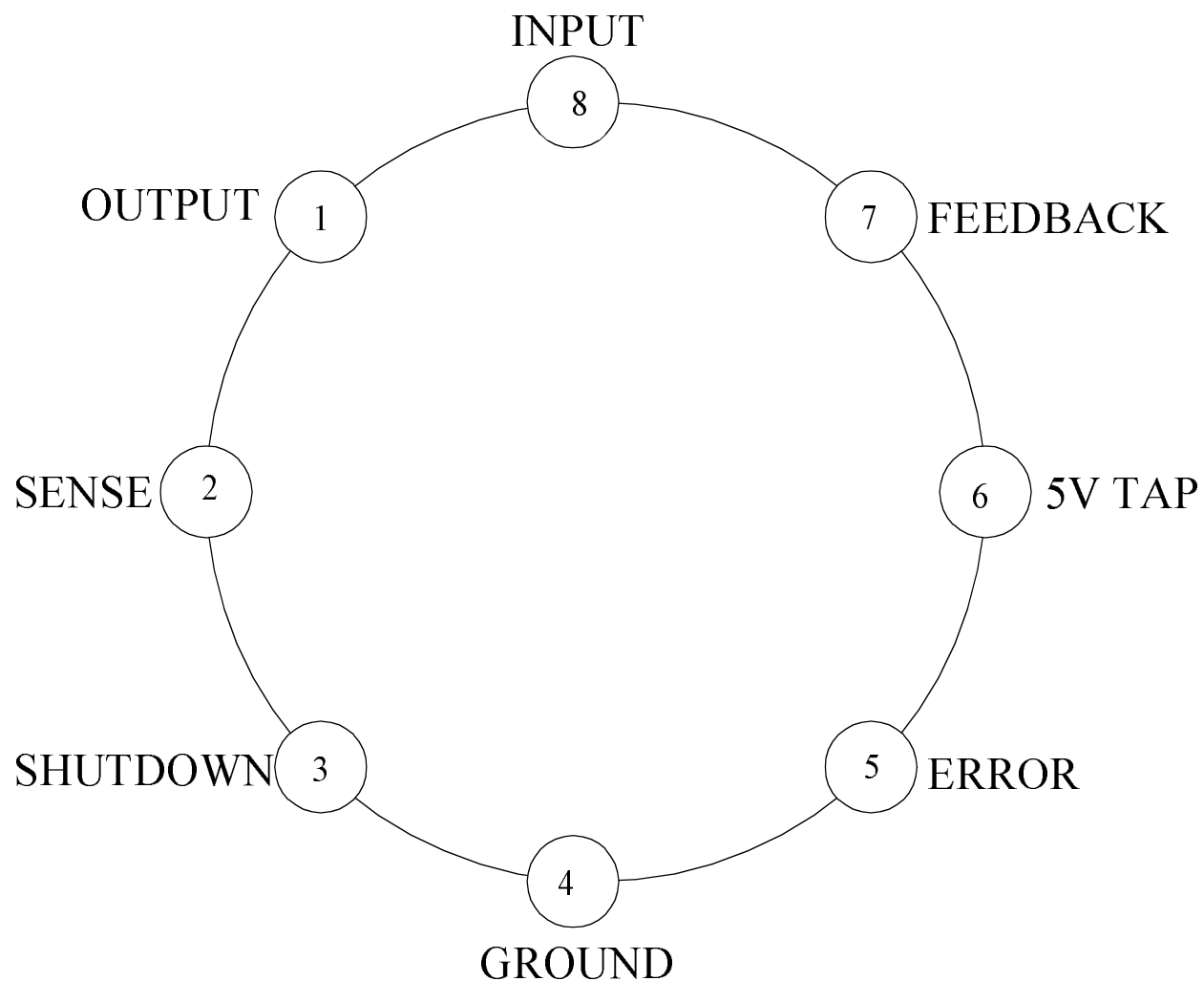
SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
Ig	Ground Current	Il = -100uA, Vin = 6V			-6.5	6.5	uA	1
Vref	Reference Voltage				-0.0055	0.0055	V	1

Note 1: Parameter tested go-no-go only.

Graphics and Diagrams

GRAPHICS#	DESCRIPTION
05810HRA2	METAL CAN (H), TO-99, 8LD, .200 DIA P.C. (B/I CKT)
06059HRA2	CERDIP (J), 8 LEAD (B/I CKT)
06146HRA2	LCC (E), TYPE C, 20 TERMINAL(B/I CKT)
06341HRA1	CERPACK (W), 10 LEAD (B/I CKT)
E20ARE	LCC (E), TYPE C, 20 TERMINAL(P/P DWG)
H08CRF	METAL CAN (H), TO-99, 8LD, .200 DIA P.C. (P/P DWG)
J08ARL	CERDIP (J), 8 LEAD (P/P DWG)
P000205A	METAL CAN (H), 8 LEAD (PINOUT)
P000206A	CERDIP (J), 8 LEAD (PINOUT)
P000251B	LCC (E), 20 LEAD (PINOUT)
P000374A	CERAMIC SOIC (WG), 10 LEAD (PINOUT)
WG10ARC	CERAMIC SOIC (WG), 10 LEAD (P/P DWG)

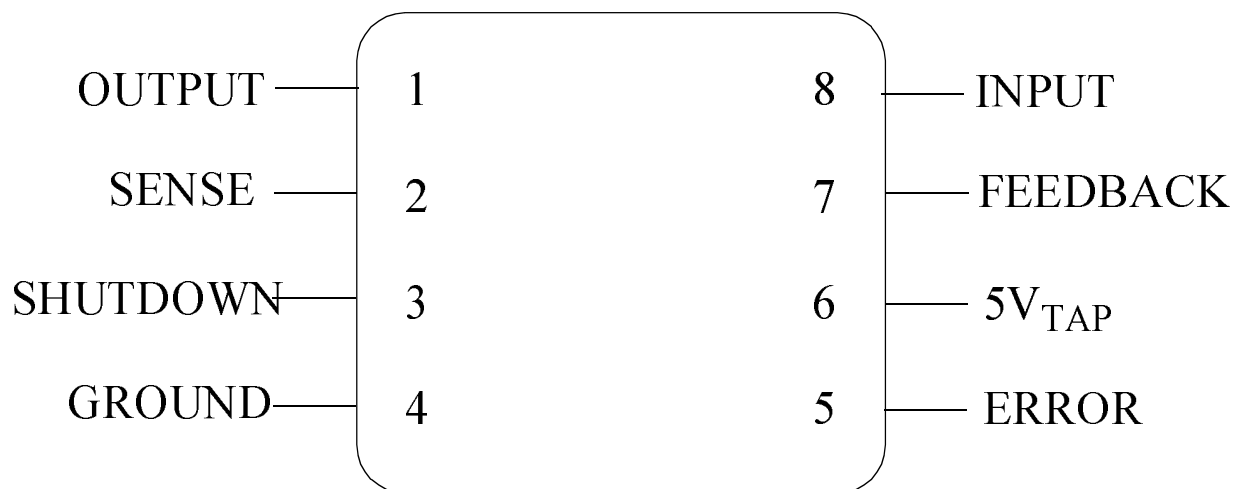
See attached graphics following this page.



LP2951H
8 - PIN METAL CAN
CONNECTION DIAGRAM
TOP VIEW
P000205A



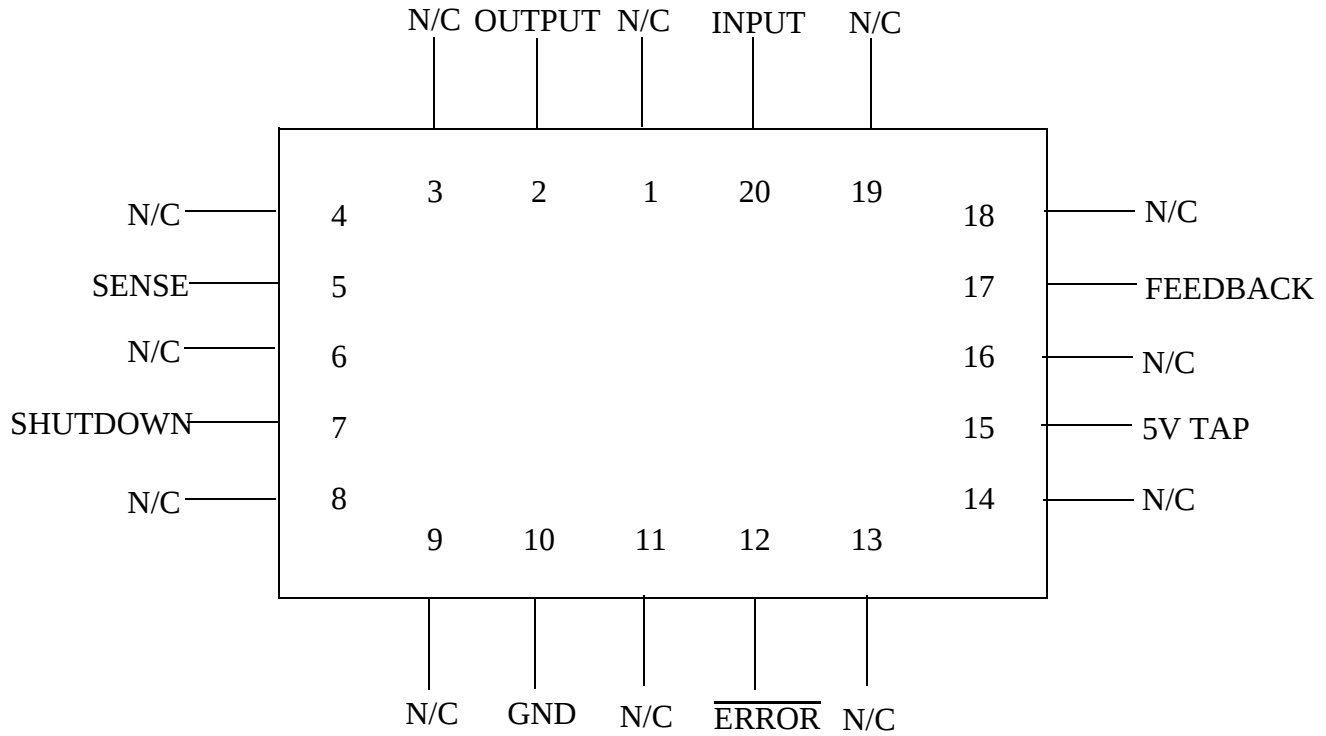
National Semiconductor™
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SANTA CLARA, CA 95050



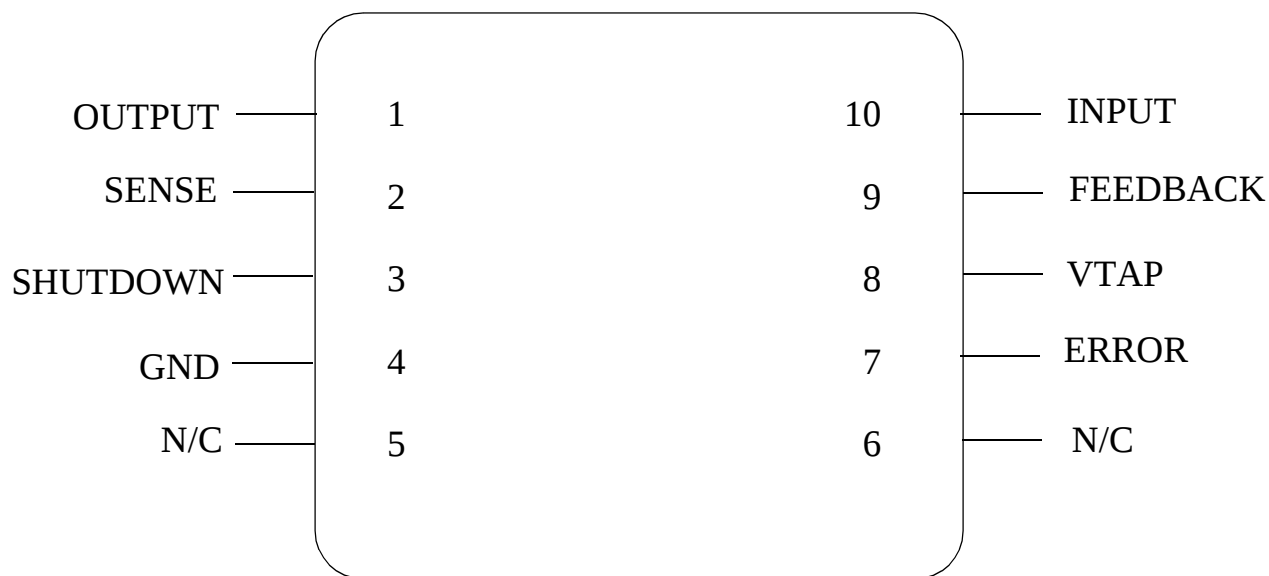
LP2951J
8 - LEAD DIP
CONNECTION DIAGRAM
TOP VIEW
P000206A



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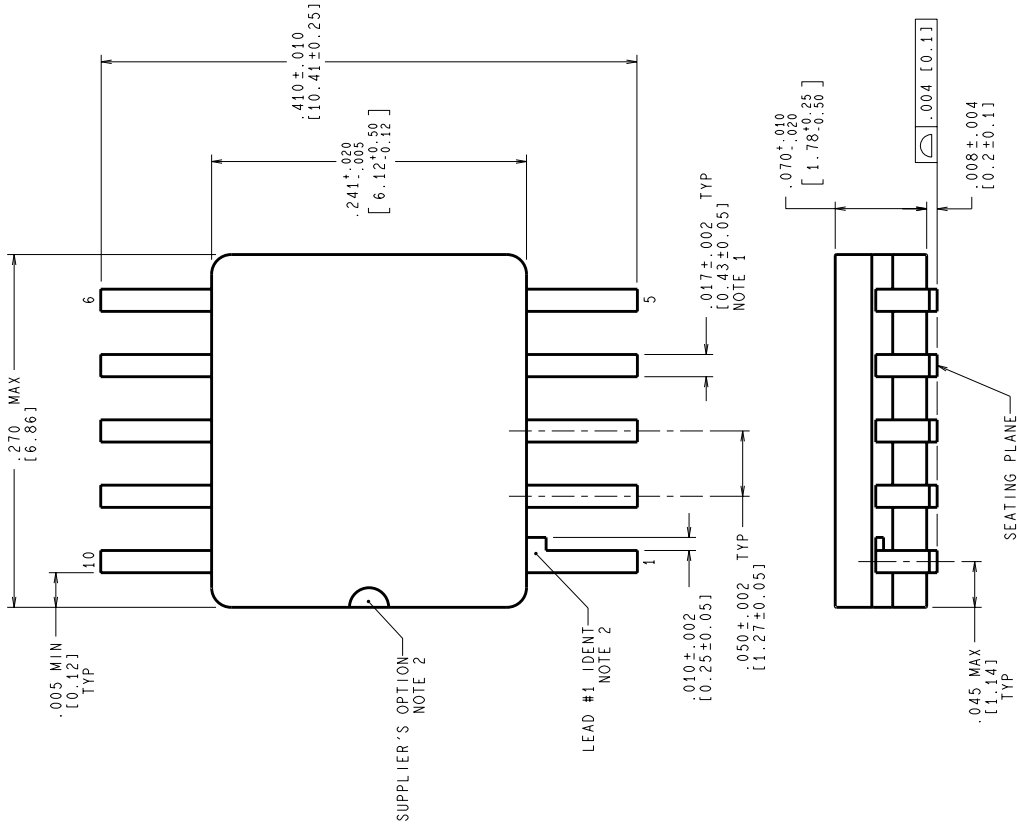
LP2951E
20 - LEAD LCC
CONNECTION DIAGRAM
TOP VIEW
P000251B



LP2951WG
10 - LEAD CERAMIC SOIC
CONNECTION DIAGRAM
TOP VIEW
P000374A

REVISIONS			
LTR	DESCRIPTION	E.C.N.	DATE
A	RELEASE TO DOCUMENT CONTROL	11374	02/29/1996
B	LD PITCH TOL WAS $\pm .005$; CHANGE LD RADIUS TO REF DIM; REMOVE THE OTHER R .006 $\pm .002$ DIM .040 $\pm .003$ WAS .037 $\pm .003$	11441	04/19/1996
C	R .015(0.38) WAS R .006(0.15)	11838	10/08/1997

BY/APP'D	DATE	MS/KH



CONTROLLING DIMENSION IS INCH
VALUES IN [] ARE MILLIMETERS

MIL-PRF-38535 CONFIGURATION CONTROL

APPROVALS	DATE	SCALE	SIZE	DRAWING NUMBER	REV
DESIGN MARTY SUCHY	02/29/96	N/A	C	(SC)MKT-WG10A	C
ENGINEER CHK.					
TESTER CHK.					
PROJECTION 					
DO NOT SCALE DRAWING SHEET 1 of 1					

National Semiconductor
2000 Semiconductor Dr., Santa Clara, CA 95052-8000

**CERPACK,
10 LEAD,
GULL WING**

- NOTES: UNLESS OTHERWISE SPECIFIED
- LEAD FINISH: SOLDER DIPPED WITH Sn60 OR Sn63 SOLDER CONFORMING TO MIL-PRF-38535 TO A MINIMUM THICKNESS OF 200 MICRONS/ 5.08 MICROMETERS. SOLDER MAY BE APPLIED OVER LEAD BASE METAL OR Sn PLATE. MAXIMUM LIMIT MAY BE INCREASED BY .003 IN/ 0.08mm AFTER LEAD FINISH APPLIED.
 - LEAD 1 IDENTIFICATION SHALL BE:
 - A NOTCH OR OTHER MARK WITHIN THIS AREA
 - A TAB ON LEAD 1, EITHER SIDE
 - NO JEDEC REGISTRATION AS OF FEBRUARY 1996.

Revision History

Rev	ECN #	Rel Date	Originator	Changes
1B1	M0002867	05/19/98	Barbara Lopez	Update MDS: MJLP2951-X Rev. 1A0 to MJLP2951-X Rev. 1B1. Updated SMD number to add suffixes. Updated NSID to add astericks associated with SMD suffix. Updated power dissipation, lead temperature, junction temperature, thermal resistance and ESD rating. Changed note 1 to Absolute note, updated note 2 to power dissipation note. Added graphics for all packages. Added Package Weights.